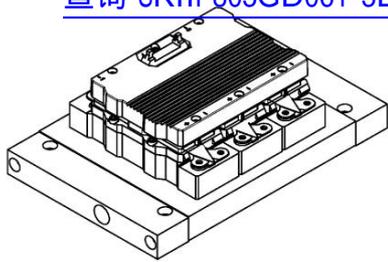


# SKiiP 803GD061-3DUW ...

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SKiiP® 3

## 6-pack-integrated intelligent power system

### Power section

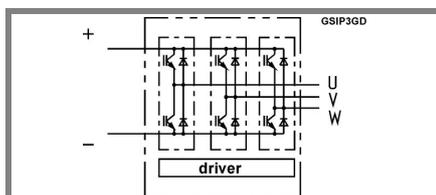
#### SKiiP 803GD061-3DUW

Preliminary Data

### Features

- SKiiP technology inside
- Low loss IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 3 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP® 3 power section)
- UL recognized File no. E63532 (SKiiP® 3 power section)

1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)



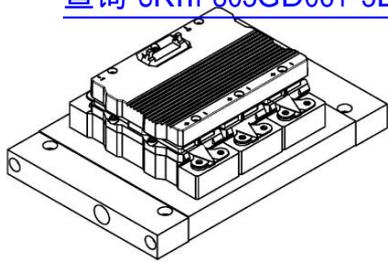
Case S33

Absolute Maximum Ratings		T <sub>s</sub> = 25°C unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
V <sub>CES</sub>	Operating DC link voltage	600	V
V <sub>CC</sub> 1)		400	V
V <sub>GES</sub>		± 20	V
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	800 (600)	A
<b>Inverse diode</b>			
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	620 (470)	A
I <sub>FSM</sub>	T <sub>j</sub> = 150 °C, t <sub>p</sub> = 10 ms; sin	6000	A
I <sup>pt</sup> (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	180	kA <sup>2</sup> s
T <sub>j</sub> ; (T <sub>stg</sub> )	rms, AC, 1min	- 40 ... + 150 (125)	°C
V <sub>isol</sub>		2500	V
I <sub>AC-terminal</sub>		per AC terminal, rms, T <sub>s</sub> = 70 °C,	400
	T <sub>terminal</sub> < 115 °C		

Characteristics		T <sub>s</sub> = 25°C unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units			
<b>IGBT</b>								
V <sub>CEsat</sub>	I <sub>C</sub> = 300 A, T <sub>j</sub> = 25 (125) °C; measured at terminal		1,5 (1,6)	1,8	V			
V <sub>CEO</sub>	T <sub>j</sub> = 25 (125) °C; at terminal		0,8 (0,7)	1 (0,9)	V			
r <sub>CE</sub>	T <sub>j</sub> = 25 (125) °C; at terminal		2,4 (3,1)	2,7 (3,4)	mΩ			
I <sub>CES</sub>	V <sub>GE</sub> = 0 V, V <sub>CE</sub> = V <sub>CES</sub> ; T <sub>j</sub> = 25 (125) °C		1,2 (36)		mA			
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 300 A, V <sub>CC</sub> = 300 V		27		mJ			
	T <sub>j</sub> = 125 °C, V <sub>CC</sub> = 400 V		39		mJ			
R <sub>CC+EE'</sub>	terminal chip, T <sub>j</sub> = 25 °C		0,5		mΩ			
L <sub>CE</sub>	top, bottom		12		nH			
C <sub>CHC</sub>	per phase, AC-side		1		nF			
<b>Inverse diode</b>								
V <sub>F</sub> = V <sub>EC</sub>	I <sub>F</sub> = 300 A, T <sub>j</sub> = 25 (125) °C; measured at terminal		1,3 (1,2)	1,5	V			
V <sub>TO</sub>	T <sub>j</sub> = 25 (125) °C		0,8 (0,6)	1 (0,8)	V			
r <sub>T</sub>	T <sub>j</sub> = 25 (125) °C		1,5 (1,9)	1,7 (2)	mΩ			
E <sub>rr</sub>	I <sub>C</sub> = 300 A, V <sub>CC</sub> = 300 V		5		mJ			
	T <sub>j</sub> = 125 °C, V <sub>CC</sub> = 400 V		6		mJ			
<b>Mechanical data</b>								
M <sub>dc</sub>	DC terminals, SI Units	6		8	Nm			
M <sub>ac</sub>	AC terminals, SI Units	13		15	Nm			
w	SKiiP® 3 System w/o heat sink		2,4		kg			
w	heat sink		5,2		kg			
<b>Thermal characteristics (NWK 40; 8l/min; 50%glyc.); "s" reference to heat sink; "r" reference to built-in temperature sensor (acc. IEC 60747-15)</b>								
R <sub>th(j-s)I</sub>	per IGBT			0,051	K/W			
R <sub>th(j-s)D</sub>	per diode			0,1	K/W			
Z <sub>th</sub>	R <sub>i</sub> (mK/W) (max. values)	tau <sub>i</sub> (s)						
		1	2	3	4			
Z <sub>th(j-r)I</sub>	4,2	20,4	23,4	0	69	0,35	0,02	1
Z <sub>th(j-r)D</sub>	7,8	12	53,1	53,1	50	5	0,25	0,04
Z <sub>th(r-a)</sub>	4,6	4,7	1,1	0,6	48	15	2,8	0,4

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SKiiP® 3

## 6-pack-integrated intelligent power system

### 6-pack integrated gate driver SKiiP 803GD061-3DUW

Preliminary Data

#### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 40/85/56 (SKiiP® 3 gate driver)

Absolute Maximum Ratings			
Symbol	Conditions	Values	Units
$V_{S2}$	unstabilized 24 V power supply	30	V
$V_i$	input signal voltage (high)	15 + 0,3	V
dv/dt	secondary to primary side	75	kV/ $\mu$ s
$V_{isolIO}$	input / output (AC, rms, 2s)	2500	V
$V_{isolPD}$	partial discharge extinction voltage, rms, $Q_{PD} \leq 10$ pC;	960	V
$V_{isol12}$	output 1 / output 2 (AC, rms, 2s)	1500	V
f	switching frequency	20	kHz
$T_{op}$ ( $T_{stg}$ )	operating / storage temperature	- 40 ... + 85	°C

Characteristics <span style="float: right;">(<math>T_a = 25^\circ\text{C}</math>)</span>					
Symbol	Conditions	min.	typ.	max.	Units
$V_{S2}$	supply voltage non stabilized	13	24	27	V
$I_{S2}$	$V_{S2} = 24$ V	$375 + 30 \cdot f / \text{kHz} + 0,00111 \cdot (I_{AC} / A)^2$			mA
$V_{IT+}$	input threshold voltage (High)	11,2			V
$V_{IT-}$	input threshold voltage (Low)	5,4			V
$R_{IN}$	input resistance	10			k $\Omega$
$C_{IN}$	input capacitance	1			nF
$t_{d(on)IO}$	input-output turn-on propagation time	1,1			$\mu$ s
$t_{d(off)IO}$	input-output turn-off propagation time	1,1			$\mu$ s
$t_{pERRRESET}$	error memory reset time	9			$\mu$ s
$t_{TD}$	top / bottom switch interlock time	3,3			$\mu$ s
$I_{analogOUT}$	max. 5mA; 8 V corresponds to 15 V supply voltage for external components	600			A
$I_{s1out}$	max. load current	50			mA
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10$ V)	750			A
$T_{tp}$	over temperature protection	110	120		°C
$U_{DCTRIP}$	$U_{DC}$ -protection ( $U_{analog OUT} = 9$ V); (option for GB types)	400			V

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